## NSN 5962-01-363-3440

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Maximum Power Dissipation Rating:
1.0 milliwatts
Operating Tempurature Range:
-55.0/+125.0 degrees celsius
Storage Tempurature Range:
-65.0/+150.0 degrees celsius
End Application:
An/gpn-22&tpn e/i fscm 49956
Features Provided:
Programmed
Inclosure Material:
Ceramic
Inclosure Configuration:
Flat pack
Output Logic Form:
Complementary-metal oxide-semiconductor logic
Case Outline Source And Designator:
F-6 mil-m-38510
Terminal Surface Treatment:
Solder
Product Name:
Microcircuit, digital fused prom
Voltage Rating And Type Per Characteristic:
-0.5 volts absolute input and 7.0 volts absolute input
Time Rating Per Chacteristic:
25.00 nanoseconds af output megawatts
Memory Device Type:
Prom
Test Data Document:
49956-g504229 drawing (this is the basic governing drawing, such as a contractor drawing, original equipment manufacturer drawing, etc.
excludes any specification, standard or other document that may be referenced in a basic governing drawing)
Terminal Type And Quantity:
24 printed circuit
Specification Data:
67268-5962-88735/tx/ government standard
Shelf Life:
N/a
Unit Of Measure:
Demilitarization:
Yes - demil/mli
Fiig:

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